

isc P-Channel MOSFET Transistor

IXTH50P10

• FEATURES

- Static drain-source on-resistance:
 $R_{DS(on)} \leq 55m\Omega @ V_{GS} = -10V$
- Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATION

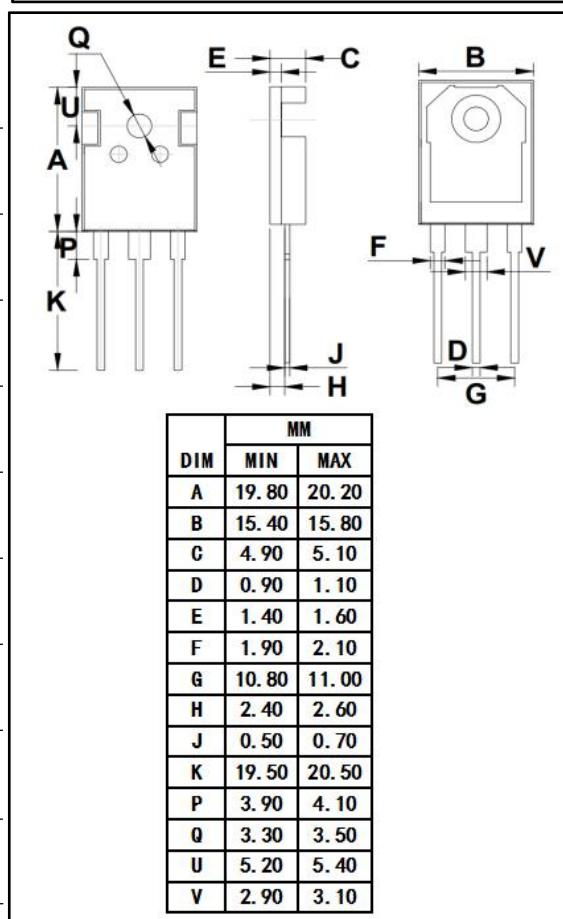
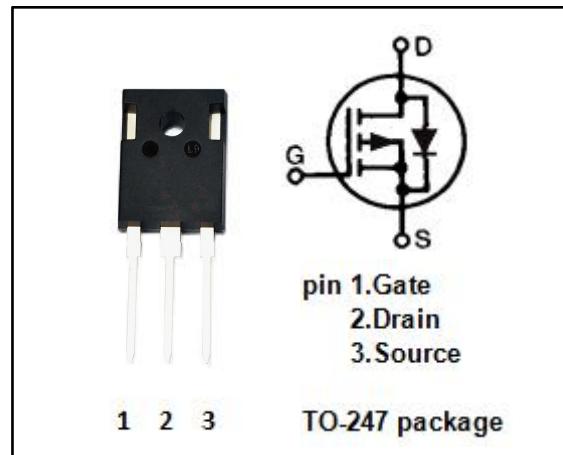
- Switched mode power supplies
- Uninterruptible power supplies

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	-100	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	-50	A
I_{DM}	Drain Current-Single Pulsed	-200	A
P_D	Total Dissipation @ $T_c=25^\circ C$	300	W
T_j	Operating Junction Temperature	-55~150	°C
T_{stg}	Storage Temperature	-55~150	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(j-c)}$	Junction-to-case thermal resistance	0.42	°C/W



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ELECTRICAL CHARACTERISTICS

 $T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}} = 0\text{V}; \text{I}_D = -250 \mu\text{A}$	-100		V
$\text{V}_{\text{GS(th)}}$	Gate Threshold Voltage	$\text{V}_{\text{DS}} = \text{V}_{\text{GS}}; \text{I}_D = -250\text{uA}$	-3	-5	V
$\text{R}_{\text{DS(on)}}$	Drain-Source On-Resistance	$\text{V}_{\text{GS}} = -10\text{V}; \text{I}_D = -25\text{A}$		55	$\text{m}\Omega$
I_{GSS}	Gate-Source Leakage Current	$\text{V}_{\text{GS}} = \pm 20\text{V}; \text{V}_{\text{DS}} = 0\text{V}$		± 100	nA
I_{DSS}	Drain-Source Leakage Current	$\text{V}_{\text{DS}} = -80\text{V}; \text{V}_{\text{GS}} = 0\text{V}$ $\text{V}_{\text{DS}} = -80\text{V}; \text{V}_{\text{GS}} = 0\text{V}; \text{T}_J = 125^\circ\text{C}$		-25 -1000	μA
V_{SD}	Diode forward voltage	$\text{I}_F = -25\text{A}; \text{V}_{\text{GS}} = 0\text{V}$		-3	V

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